SP4T RF Switch

JSW4-272DR+

 50Ω 5 to 2700 MHz High Power 3W

The Big Deal

- High Port count in super small size
- Single Positive Supply Voltage, 2.5 4.8V
- High Power P0.1dB, 3W typ.
- Low Insertion Loss, 0.6 dB at 1 GHz



Product Overview

JSW4-272DR+ is a high power reflective SP4T RF switch, with reflective short on output ports in the off condition. Made using Silicon-on-Insulator process, it has very high IP3, a built-in CMOS driver and negative voltage generator. Its tiny 2x2mm, 14-lead case enables wideband performance in tight spaces and dense PCB layouts.

Key Features

| Feature | Advantages |
|---|--|
| Wideband operation 5-2700 MHz | Enables a single component to be used in a vast array of applications from VHF up to 2.7 GHz. |
| High IIP3: 55 dBm typ. | Results in little or negligible inter-modulation generation, meeting requirements for digital communication signals. |
| Low Loss, 0.6 dB at 1 GHz High input power, 3W | Low loss and high power capability enable a single switch to be used for a variety of applications, saving inventory. |
| Built in negative voltage generator | Operates with a single positive supply voltage; no need for DC blocking capacitors, unless external DC is present at the RF ports. |
| Built-in CMOS driver | No need for external driver, saving PCB space and cost. |
| Tiny MCLP package 2 x 2mm, 14-lead | Provides low inductance, repeatable transitions, and excellent thermal contact to PCB. |

Reflective RF Switch with internal driver. Single Supply Voltage, +2.5V to +4.8V, High Power 3W

Product Features

- High Isolation, 37 dB typ. at 1 GHz
- Low insertion loss, 0.6 dB typ. at 1 GHz
- High IP3, 59 dBm typ. at 1 GHz
- Low current consumption, 40 µA typ.
- High Power, P0.1dB 3W typ.

Typical Applications

- CATV systems
- SATCOM system
- Automated Test Stations
- Telecom systems

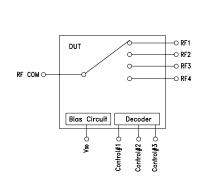


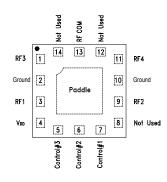
+RoHS Compliant
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

General Description

JSW4-272DR+ is a high power 3W reflective SP4T switch with integral driver, operates with single positive supply voltage while consuming, $40 \,\mu\text{A}$ typical. It has been designed for very wideband operation of 5-2700 MHz. It is packaged in a tiny 14-lead 2mm x 2mm x 0.55mm package and is rated MSL1 and class 1B ESD.

Simplified Schematic and Pad Description





| Function | Pad Number | Description | Function | Pad Number | Description |
|----------|---------------|----------------------|------------|---------------|-------------------|
| RF COM | 13 | RF Common/ SUM Port | Control #1 | 7 | Control IN #1 |
| RF1 | 3 | RF Out #1/In Port #1 | Control #2 | 6 | Control IN #2 |
| RF2 | 9 | RF Out #2/In Port #2 | Control #3 | 5 | Control IN #3 |
| Ground | 2 | Ground Externally | VDD | 4 | Supply Voltage |
| Ground | 10 | Ground Externally | Ground | Paddle | Ground Externally |
| RF3 | 1 | RF Out #5/In Port #5 | Not Used | 8,12,14 | No Connection |
| BF4 | 11 | BE Out #6/In Port #6 | | | |

RF Electrical Specifications⁽¹⁾, 5 - 2700 MHz, T_{AMB} =25°C, V_{DD} = +2.5 to 4.8V

| Parameter | Condition (MHz) | Min. | Тур. | Max. | Units |
|--|-----------------|------|------|------|-------|
| Frequency Range | | 5 | | 2700 | MHz |
| | 5 to 1000 | _ | 0.6 | 0.8 | |
| Insertion Loss ⁽²⁾ | 1000 to 2000 | _ | 0.6 | 0.8 | dB |
| | 2000 to 2700 | _ | 0.6 | 0.8 | |
| | 5 to 1000 | 35 | 37 | _ | |
| Isolation between Common Port and RF1 to RF4 Ports (3) | 1000 to 2000 | 28 | 30 | _ | dB |
| | 2000 to 2700 | 25 | 27 | _ | |
| | 5 to 1000 | _ | 15.5 | _ | |
| Return Loss (ON STATE) RF-COM, RF1 to RF4 Ports | 1000 to 2000 | _ | 14.2 | _ | dB |
| | 2000 to 2700 | _ | 14.3 | _ | |
| Input IP3 V _{DD} =2.5 to 4.8V | 5 to 500 | _ | 55 | _ | dD. |
| V _{DD} =3.0V | 1000 to 2700 | _ | 59 | _ | dBm |
| 0.1dB Input Compression ⁽⁴⁾ | 5 to 2700 | _ | 35 | _ | dBm |

DC Electrical Specifications

| Parameter | Min. | Тур. | Max. | Units |
|--|------|------|------|-------|
| VDD, Supply Voltage | 2.5 | 3.0 | 4.8 | V |
| Supply Current (V _{DD} = 3V) | | 40 | | μΑ |
| Control Voltage Low | 0 | | 0.4 | V |
| Control Voltage High ⁽⁵⁾ | 1.35 | 1.8 | 2.7 | V |
| Control Current | | 0.5 | 1.0 | μΑ |
| Shutdown Current at V _{DD} = 3V | | 5 | | μA |

Notes:

- Notes.

 1. As measured in Mini-Circuit's test board TB-724-4+ (see Characterization Test Circuit, Fig.1).

 2. Insertion loss values are de-embedded from test board loss.

- 3. Isolations for other port combinations, see Tables 1 & 2
 4. Do not exceed RF input power as shown in Absolute Maximum Rating table.
 5. If V_{DD} <2.7V, then Max Control Voltage high=V_{DD}

Switching Specifications

| Parameter | Min. | Тур. | Max. | Units |
|---|------|--------------------------------------|------|------------|
| Rise/Fall Time (10 to 90% or 90 to 10% RF) | _ | 0.42 (Rise Time) 0.84 (Fall Time) | _ | μSec |
| Switching Time, 50% CTRL to 90/10% RF | _ | 1.9 (ON Time) 1.4 (OFF Time) | _ | μSec |
| Video Feedthrough, (control 0 to 1.65V, freq.=10 KHz) | _ | 3.0 | _ | mV_{P-P} |

Table 1. Isolation Matrix (RF-COM to RF1 to RF4 Ports)

| | Frequency (GHz) | Isolation Typ. (dB) "ON" Port | | | |
|----------------|--------------------|----------------------------------|-----|-----|-----|
| RF Com to Port | | RF1 | RF2 | RF3 | RF4 |
| RF1 | 0.01-1.0 | | 49 | 53 | 49 |
| RF1 | 1.0-2.0 | | 43 | 38 | 43 |
| RF1 | 2.0-2.7 | | 40 | 34 | 39 |
| RF2 | 0.01-1.0 | 48 | | 48 | 50 |
| RF2 | 1.0-2.0 | 43 | | 42 | 38 |
| RF2 | 2.0-2.7 | 39 | | 39 | 33 |
| RF3 | 0.01-1.0 | 44 | 39 | | 40 |
| RF3 | 1.0-2.0 | 33 | 34 | | 34 |
| RF3 | 2.0-2.7 | 28 | 31 | | 31 |
| RF4 | 0.01-1.0 | 39 | 41 | 40 | |
| RF4 | 1.0-2.0 | 33 | 32 | 34 | |
| RF4 | 2.0-2.7 | 31 | 28 | 31 | |

Table 2. Isolation Matrix (Between Output Ports)

| | Frequency (GHz) | Isolation Typ. (dB) "ON" Port & to Port | | | |
|-----------|--------------------|---|-----|-----|-----|
| From Port | | RF1 | RF2 | RF3 | RF4 |
| RF1 | 0.01-1.0 | | 54 | 37 | 55 |
| RF1 | 1.0-2.0 | | 45 | 32 | 46 |
| RF1 | 2.0-2.7 | | 41 | 28 | 42 |
| RF2 | 0.01-1.0 | 54 | | 55 | 37 |
| RF2 | 1.0-2.0 | 44 | | 45 | 32 |
| RF2 | 2.0-2.7 | 40 | | 41 | 29 |
| RF3 | 0.01-1.0 | 44 | 58 | | 48 |
| RF3 | 1.0-2.0 | 37 | 45 | | 40 |
| RF3 | 2.0-2.7 | 32 | 42 | | 37 |
| RF4 | 0.01-1.0 | 45 | 44 | 48 | |
| RF4 | 1.0-1.5 | 38 | 37 | 39 | |
| RF4 | 1.5-2.0 | 36 | 32 | 37 | |

Absolute Maximum Ratings(6)

| Parameter | Ratings |
|----------------------------------|---------------------|
| Operating Temperature | -40°C to +85°C |
| Storage Temperature | -55°C to 150°C |
| V _{DD} , Supply Voltage | 5.0V |
| Voltage Control | -0.5V Min. 3.0 Max. |
| RF input power ⁽⁷⁾ | 5 Watt |

^{6.} Operation of this device above any of these conditions may cause permanent damage.

Truth Table(8) (State of control voltage selects the desired switch state)

| State of Control Voltages | | | | RF Con | nmon to | |
|---------------------------|------------|------------|----------|--------|---------|-----|
| Control #1 | Control #2 | Control #3 | RF1 | RF2 | RF3 | RF4 |
| L | L | L | ON | _ | _ | _ |
| L | L | Н | _ | ON | _ | _ |
| Н | L | L | _ | _ | ON | _ |
| Н | L | Н | _ | _ | _ | ON |
| Н | Н | Н | Shutdown | | | |

^{8.} Any control state not defined above, places the switch in an undefined state, but will not damage the switch.

Characterization Test Circuit

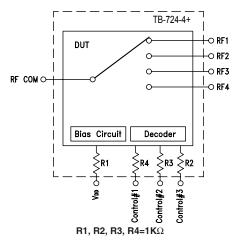


Figure 1: Block Diagram Of Test Circuit Used For Characterization. (DUT soldered on Mini-Circuits' TB-724-4+)

Test Equipment:

For Insertion loss, Isolation, Return loss:

Agilent's N5230A Network Analyzer, E3631A power supply.

For Switching Time and Video Feed through

Agilent's HP81110A pulse generator, 54833A Oscilloscope, E3631A power supply. Agilent's N9020A Spectrum Analyzer, E8257D Generator, E3631A power supply

For Compression:

R&S Network Analyzer ZVA24, E3631A power supply.

Conditions:

 $V_{_{DD}}=+2.5, +3.0$ and +4.8V, Control= 0 and 1.35V. For Insertion loss, isolation and return loss: Pin=0 dBm

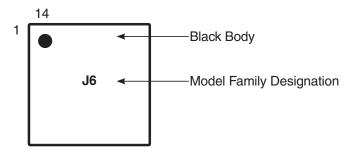
For Input IP3: Pin=+10dBm/tone at $V_{DD}=3V$

For Switching time: RF frequency: DC at 200mV, Control Frequency: 10 KHz and 0 and +8V.

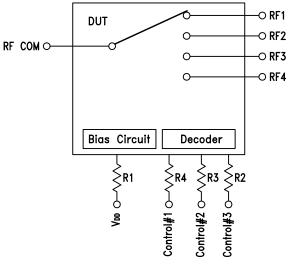


^{7.} Derate linearly to 2.5W at 85°C.

Product Marking



Recommended Application Circuit



R1, R2, R3, R4=1k Ω

| Additional Detailed Technical Information additional information is available on our dash board. To access this information click here | | | |
|--|---|--|--|
| Performance Data | Data Table | | |
| Performance Data | Swept Graphs | | |
| Case Style | MT1817 Plastic package; Lead finish: Matte Tin | | |
| Tape & Reel | F108 | | |
| Standard quantities available on reel | 7" reels with 20, 50, 100, 200, 500, 1K or 3K devices | | |
| Suggested Layout for PCB Design | PL-462 | | |
| Evaluation Board | TB-724-4+ | | |
| Environmental Ratings | ENV75 | | |

ESD Rating

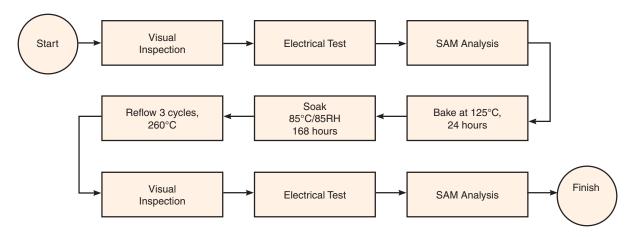
Human Body Model (HBM): Class 1B (500 to < 1000V) in accordance with JESD22-A114

Machine Model (MM): Class A (Pass 100V) in accordance with JESD22-A115

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

MSL Test Flow Chart



Additional Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
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